

## 520nm GREEN Laser Diode



## D6-6-520-30

## Application

Industrial use Biomedical

## Property

Wavelength λ = 520 nm Output Power = 30 mW Package Type = φ 5.6mm

## Introduction

Egismos currently markets InGaN-based green laser diodes 515-520nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer. Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.

## Red Laser Diode Key features

### Absolute Maximum Rating at Tc=25°C

Items	Symbols	Values	Unit
Operating Current power	Po	30	mW
Reverse Voltage	V <sub>R</sub>	2	V
Operating Temperature	T <sub>case</sub>	-10~+60	°C
Storage Temperature	Ts	-40~+85	°C

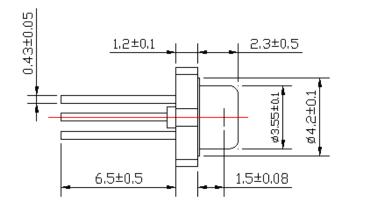


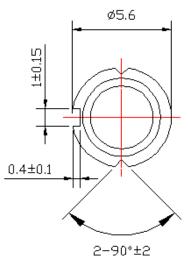
# EGISMOS 520nm GREEN Laser Diode

#### Electrical and Optical Characteristics at Tc= $25^{\circ}$ C

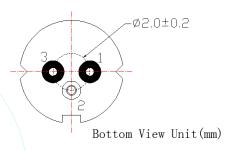
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Item	Symbols	Min	Тур.	Max.	Unit	Condition
Threshold Current	I <sub>th</sub>	-	50	75	mA	-
Operating Current	l <sub>op</sub>	-	120	140	mA	Po=30mW
Operating Voltage	V <sub>op</sub>	-	6.7	8.0	V	Po=30mW
Peak Wavelength	λp	510	520	530	nm	Po=30mW
Beam Divergence (FWHM)	θ″	4	7	11	deg	Po=30mW
Beam Divergence (FWHM)	θ⊥	16	22	25	deg	Po=30mW

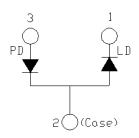
## Package Drawing





## **ELECTRICAL CONNECTION**





Specifications are subject to change without notice.





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